

INVENTOR INFORMATION

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APPLICATION INFORMATION

Title Line One:: TRAVELING WAVE OPTICAL MODULATORS
Total Drawing Sheets:: 4
Formal Drawings?: Yes
Application Type:: Utility
Docket Number:: 782_141
Secrecy Order in Parent Appl.?: No

REPRESENTATIVE INFORMATION

Parameter	Value	Unit
Temperature	25.0	°C
Pressure	1.0	atm
Flow rate	1.0	L/min
Wavelength	254	nm
Scan rate	10	nm/min
Integration time	10	s
Resolution	0.5	nm
Slit width	1.0	mm
Detector	Photodiode array	
Sample volume	10	μL
Injection volume	1	μL
Mobile phase	Water/Acetonitrile	
Gradient	0-100% ACN in 10 min	
Column	C18, 150 × 4.6 mm	
Particle size	5	μm
Porosity	100	Å
Flow rate	1.0	mL/min
Temperature	30	°C
Wavelength	254	nm
Scan rate	10	nm/min
Integration time	10	s
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Integration time	10	s
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Detector	Phot	

Foreign Application One:: 11-355,335
Filing Date:: 12-15-1999
Country:: Japan
Priority Claimed:: Yes

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